

Transient Voltage Suppressors for ESD Protection

voltage eve leakage, an ideal for ESI is at a premi Applicatio • Cellular • Portabl	ons r phones le devices	 Peak Power up to 200 Watts @ 8 x 20 _µs Pulse 				
Digital ofPower s	harge) 5-7 Class 3 Model)					
Functiona	al diagram					
	al diagram SOD-523 Ratings (T _{amb} =25°C)					
	SOD-523		Value	Units		
Absolute	SOD-523 Ratings (T _{amb} =25°C)		Value 200	Units		
Absolute Symbol	SOD-523 Ratings (T _{amb} =25°C) Parameter	luring 10s				
Absolute Symbol Ppp	$SOD-523$ $Ratings (T_{amb}=25^{\circ}C)$ $Parameter$ $Peak Pulse Power (t_{p} = 8/20 \mu s)$	luring 10s	200	W		
Absolute Symbol Ppp TL	SOD-523 Ratings (T _{amb} =25°C) Peak Pulse Power (t _p = 8/20µs) Maximum lead temperature for soldering d	luring 10s	200 260	W °C		
Absolute Symbol PPP TL Tstg	SOD-523 Ratings (T _{amb} =25°C) Parameter Peak Pulse Power (t _p = 8/20μs) Maximum lead temperature for soldering d Storage Temperature Range	luring 10s	200 260 -55 to +155	W °C °C		
Absolute Symbol PPP TL Tstg Top	SOD-523 SOD-523 Ratings (T _{amb} =25°C) Parameter Peak Pulse Power (t _p = 8/20µs) Maximum lead temperature for soldering d Storage Temperature Range Operating Temperature Range	luring 10s	200 260 -55 to +155 -40 to +125	W °C °C °C		

ESD Voltage

Per Human Body Model

Per Machine Model

kV

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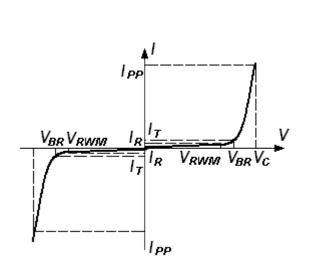
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400



Electrical Parameter

Symbol	Parameter						
I _{PP}	Maximum Reverse Peak Pulse Current						
Vc	Clamping Voltage @ IPP						
V _{RWM}	Working Peak Reverse Voltage						
I _R	Maximum Reverse Leakage Current @ V _{RWM}						
Ι _Τ	Test Current						
V_{BR}	Breakdown Voltage @ I _T						



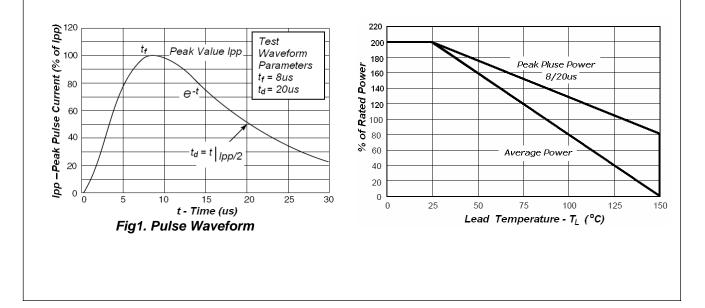
Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.VF = 0.9V at IF = 10mA

	V _{BR}					VF	IF	С	
Part Numbers	Min.	Тур.	Max.	IT	V _{RWM}	IR	Max.	Тур.	Typ. 0v bias
	V	V	V	mA	V	μA	V	mA	pF
SLESD5Z3V3C	5.1	6.0	6.8	1	3.3	1	-	-	20
SLESD5Z5C	5.6	6.7	7.8	1	5.0	1	-	-	30

*Surge current waveform per Figure 1.

1. V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25° C.

Typical Characteristics





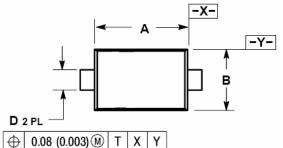
Application Note

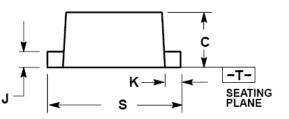
Electrostatic discharge (ESD) is a major cause of failure in electronic systems. Transient Voltage Suppressors (TVS) are an ideal choice for ESD protection. They are capable of clamping the incoming transient to a low enough level such that damage to the protected semiconductor is prevented.

Surface mount TVS offers the best choice for minimal lead inductance. They serve as parallel protection elements, connected between the signal lines to ground. As the transient rises above the operating voltage of the device, the TVS becomes a low impedance path diverting the transient current to ground.

The tiny SOD-523 package allows design flexibility in the design of high density boards where the space saving is at a premium. This enables to shorten the routing and contributes to hardening against ESD.

SOD-523 Mechanical Data





Dim		Millimeters		INCHES			
	MIN	NOM	MAX	MIN	NOM	MAX	
A	1.10	1.20	1.30	0.043	0.047	0.051	
В	0.70	0.80	0.90	0.028	0.032	0.035	
С	0.50	0.60	0.70	0.020	0.024	0.028	
D	0.25	0.30	0.35	0.010	0.012	0.014	
J	0.07	0.14	0.20	0.0028	0.0055	0.0079	
K	0.15	0.20	0.25	0.006	0.008	0.010	
S	1.50	1.60	1.70	0.059	0.063	0.067	